

# 20 V, 1.2 A P-channel Trench MOSFET Rev. 2 — 6 December 2011

Product data sheet

#### **Product profile** 1.

### **1.1 General description**

P-channel enhancement mode Field-Effect Transistor (FET) in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### **1.2 Features and benefits**

- 1.8 V R<sub>DSon</sub> rated
- Very fast switching

### **1.3 Applications**

- Relay driver
- High-speed line driver

- Trench MOSFET technology
- High-side loadswitch
- Switching circuits

### 1.4 Quick reference data

Table 1.	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V
$V_{GS}$	gate-source voltage			-8	-	8	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ 25 °C	<u>[1]</u>	-	-	-1.2	А
Static cha	aracteristics						
$R_{DSon}$	drain-source on-state resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -1.2 A; T <sub>j</sub> = 25 °C		-	170	210	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

#### **Pinning information** 2.

1.1

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		-
2	S	source		
3	D	drain		G (F)
			SOT23 (TO-236AB)	S 017aaa257



# 3. Ordering information

Version
SOT23

### 4. Marking

#### Table 4.Marking codes

Type number	Marking code <sup>[1]</sup>
PMV160UP	NH%

[1] % = placeholder for manufacturing site code

### 5. Limiting values

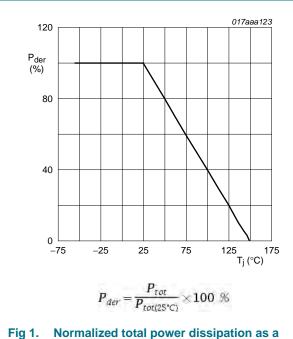
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

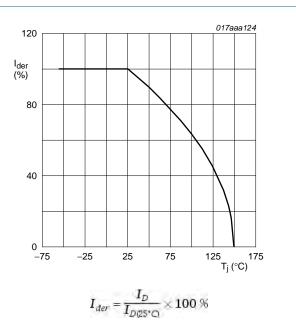
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-20	V
V <sub>GS</sub>	gate-source voltage			-8	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> 25 °C	<u>[1]</u>	-	-1.2	А
		$V_{GS}$ = -4.5 V; $T_{amb}$ = 100 °C	<u>[1]</u>	-	-0.8	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-4	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	335	mW
			[1]	-	480	mW
		T <sub>sp</sub> = 25 °C		-	2170	mW
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-dra	in diode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	<u>[1]</u>	-	-0.5	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



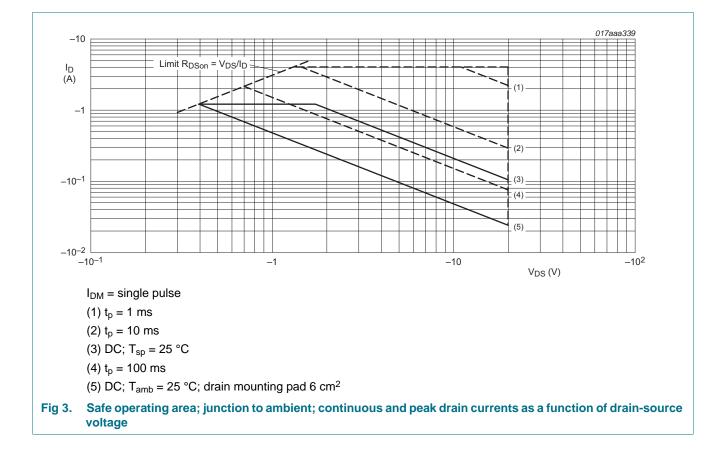
function of junction temperature





# **PMV160UP**

### 20 V, 1.2 A P-channel Trench MOSFET

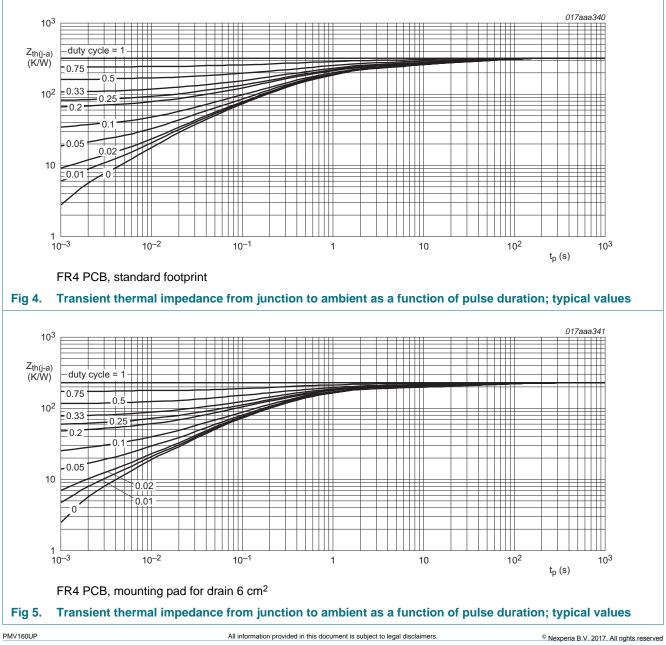


### 6. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance	in free air	<u>[1]</u>	-	325	374	K/W
	from junction to ambient		[2]	-	227	260	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	50	60	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

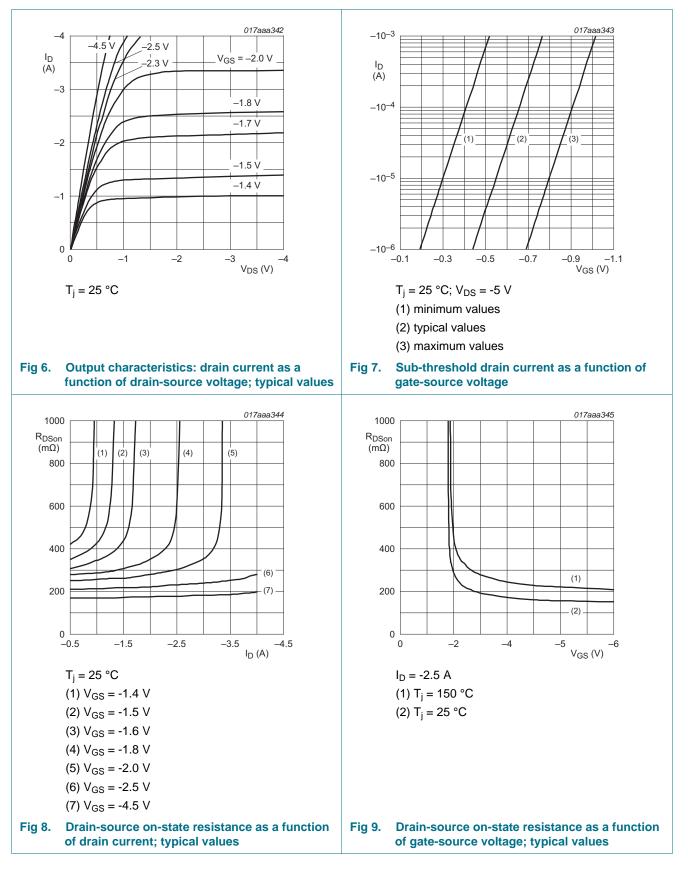


### 7. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-0.45	-0.7	-0.95	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = -20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
		$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	-10	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS} = -8 \text{ V}; V_{DS} = 0 \text{ V}; \text{ T}_{j} = 25 \text{ °C}$	-	-	-100	nA
		$V_{GS} = 8 \text{ V};  V_{DS} = 0 \text{ V};  \text{T}_{j} = 25 ^{\circ}\text{C}$	-	-	-100	nA
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -1.2 A; T <sub>j</sub> = 25 °C	-	170	210	mΩ
	resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -1.2 A; T <sub>j</sub> = 150 °C	-	- 265	328	mΩ
		$V_{GS}$ = -2.5 V; I <sub>D</sub> = -1.1 A; T <sub>j</sub> = 25 °C	- 210	270	mΩ	
		$V_{GS}$ = -1.8 V; I <sub>D</sub> = -0.5 A; T <sub>j</sub> = 25 °C	-	280	380	mΩ
9 <sub>fs</sub>	forward transconductance	$V_{DS} = -5 \text{ V}; \text{ I}_{D} = -1.2 \text{ A}; \text{ T}_{j} = 25 \text{ °C}$	-	3.7	-	S
Dynamic o	characteristics					
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -10 V; $I_{D}$ = -1 A; $V_{GS}$ = -4.5 V;	-	3.3	4	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1	-	nC
Q <sub>GD</sub>	gate-drain charge		-	0.5	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = -10 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	365	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	42	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	30	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -10 V; $V_{GS}$ = -4.5 V; $R_{G(ext)}$ = 6 $\Omega$ ;	-	7	-	ns
t <sub>r</sub>	rise time	T <sub>j</sub> = 25 °C; I <sub>D</sub> = -1 A	-	26	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	35	-	ns
t <sub>f</sub>	fall time		-	17	-	ns
Source-dr	ain diode					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -0.5 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.7	-1.2	V

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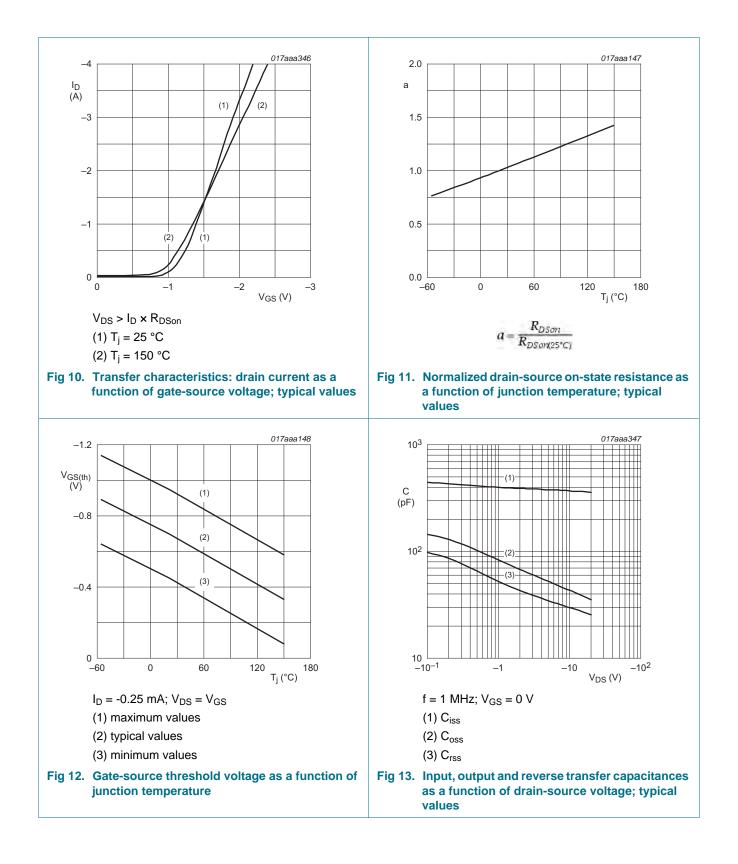
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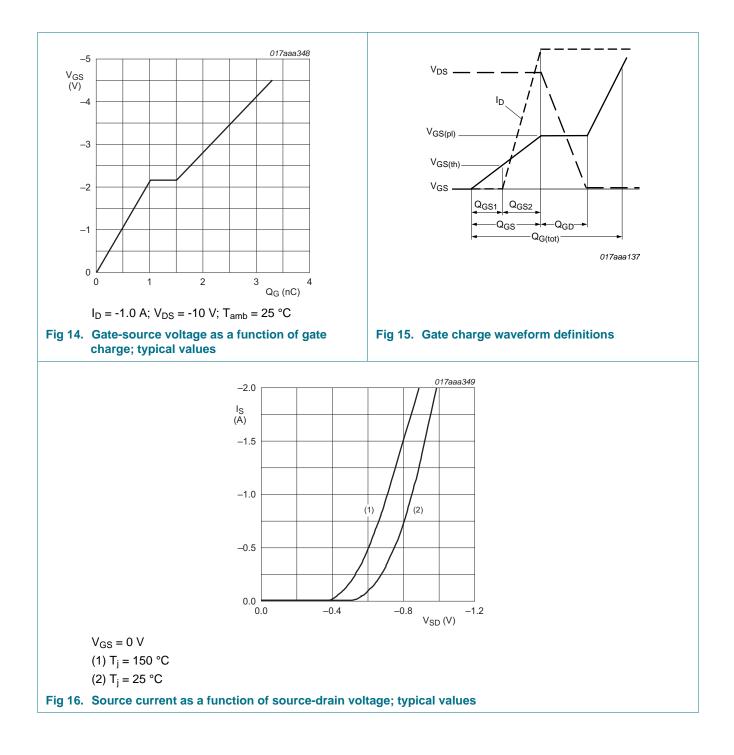
# **PMV160UP**

### 20 V, 1.2 A P-channel Trench MOSFET



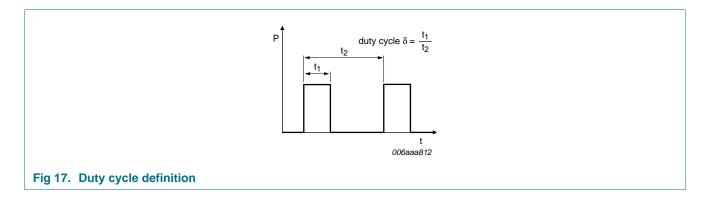
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### 20 V, 1.2 A P-channel Trench MOSFET

# 8. Test information



20 V, 1.2 A P-channel Trench MOSFET

### 9. Package outline

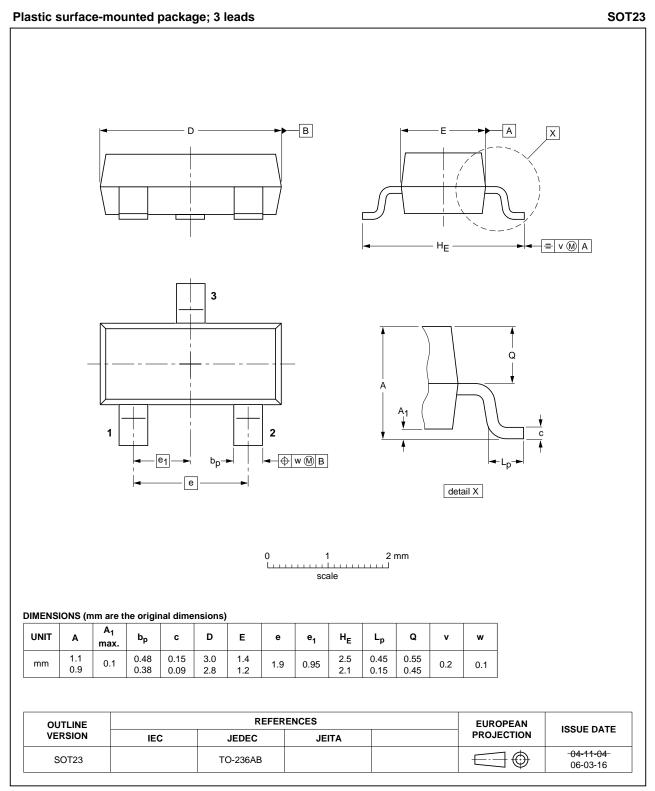
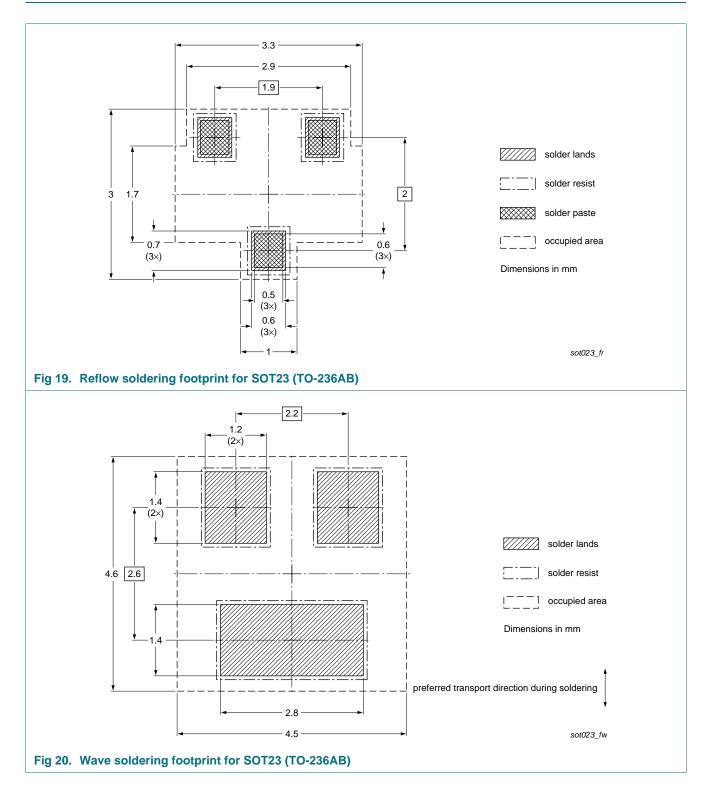


Fig 18. Package outline SOT23 (TO-236AB)

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### 20 V, 1.2 A P-channel Trench MOSFET

### 10. Soldering



Rev. 2 — 6 December 2011

# **11. Revision history**

Table 8.Revision	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMV160UP v.2	20111206	Product data sheet	-	PMV160UP v.1
Modifications:	• 7 "Character	istics": V <sub>GSth</sub> condition is corr	ected	
PMV160UP v.1	20110907	Product data sheet	-	-

### **12. Legal information**

### **12.1 Data sheet status**

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

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Rev. 2 — 6 December 2011

### 20 V, 1.2 A P-channel Trench MOSFET

### 14. Contents

1	Product profile1
1.1	General description1
1.2	Features and benefits1
1.3	Applications1
1.4	Quick reference data1
2	Pinning information2
3	Ordering information2
4	Marking
5	Limiting values
6	Thermal characteristics5
7	Characteristics6
8	Test information10
9	Package outline11
10	Soldering12
11	Revision history13
12	Legal information14
12.1	Data sheet status14
12.2	Definitions14
12.3	Disclaimers
12.4	Trademarks15
13	Contact information15



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